

MOC3031M MOC3032M MOC3033M MOC3041M MOC3042M MOC3043M

DESCRIPTION

The MOC303XM and MOC304XM devices consist of a AlGaAs infrared emitting diode optically coupled to a monolithic silicon detector performing the function of a zero voltage crossing bilateral triac driver.

They are designed for use with a triac in the interface of logic systems to equipment powered from 115 VAC lines, such as teletypewriters, CRTs, solid-state relays, industrial controls, printers, motors, solenoids and consumer appliances, etc.

FEATURES

- Simplifies logic control of 115 VAC power
- Zero voltage crossing
- dv/dt of 2000 V/μs typical, 1000 V/μs guaranteed
- VDE recognized (File # 94766) -ordering option V (e.g., MOC3043VM)

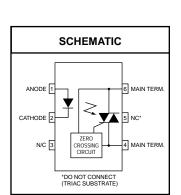
APPLICATIONS

- Solenoid/valve controls
- Lighting controls
 AC motor drives
- Static power switchesTemperature controls
- E.M. contactors
- AC motor starters
- Solid state relays

ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise noted)						
Parameters	Symbol	Device	Value	Units		
TOTAL DEVICE	т	All	-40 to +150	°C		
Storage Temperature	T _{STG}	All	-40 10 +150			
Operating Temperature	T _{OPR}	All	-40 to +85	°C		
Lead Solder Temperature	T _{SOL}	All	260 for 10 sec	°C		
Junction Temperature Range	Т _Ј	All	-40 to +100	°C		
Isolation Surge Voltage ⁽¹⁾ (peak AC voltage, 60Hz, 1 sec duration)	V _{ISO}	All	7500	Vac(pk)		
Total Device Power Dissipation @ 25°C	Р	All	250	mW		
Derate above 25°C	P _D	All	2.94	mW/°C		
EMITTER	I	All	60	mA		
Continuous Forward Current	١ _F	All	00	ША		
Reverse Voltage	V _R	All	6	V		
Total Power Dissipation 25°C Ambient	Р	All	120	mW		
Derate above 25°C	PD	All	1.41	mW/°C		
DETECTOR	N/	MOC3031M/2M/3M	250	V		
Off-State Output Terminal Voltage	V _{DRM}	MOC3041M/2M/3M	400	V		
Peak Repetitive Surge Current (PW = 100 µs, 120 pps)	I _{TSM}	All	1	A		
Total Power Dissipation @ 25°C Ambient	Р	All	150	mW		
Derate above 25°C	PD	All	1.76	mW/°C		

Note

1. Isolation surge voltage, V_{ISO}, is an internal device dielectric breakdown rating. For this test, Pins 1 and 2 are common, and Pins 4, 5 and 6 are common.





MOC3031M M0

MOC3032M MOC3033M

MOC3041M

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ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ Unless otherwise specified)

INDIVIDUAL COMPONENT CHARACTERISTICS

Parameters	Test Conditions	Symbol	Device	Min	Тур	Max	Units
EMITTER	L 00 A		A 11		4.05	4.5	
Input Forward Voltage	I _F = 30 mA	V _F	All		1.25	1.5	V
Reverse Leakage Current	V _R = 6 V	I _R	All		0.01	100	μA
DETECTOR							
Peak Blocking Current, Either Direction	Rated V_{DRM} , $I_F = 0$ (note 1)	I _{DRM1}	All			100	nA
Peak On-State Voltage, Either Direction	$I_{TM} = 100 \text{ mA peak}, I_F = 0$	V _{TM}	All		1.8	3	V
Critical Rate of Rise of Off-State Voltage	$I_F = 0$ (figure 9, note 3)	dv/dt	All	1000			V/µs

TRANSFER CHARACTERISTICS (T_A = 25°C Unless otherwise specified.)

DC Characteristics	Test Conditions	Symbol	Device	Min	Тур	Max	Units
LED Trigger Current	Main terminal voltage = 3V (note 2)	I _{FT}	MOC3031M/MOC3041M			15	
			MOC3032M/MOC3042M			10	mA
			MOC3033M/MOC3043M			5	
Holding Current, Either Direction		Ι _Η	All		400		μA

ZERO CROSSING CHARACTERISTICS (T _A = 25°C Unless otherwise specified.)							
Characteristics	Test Conditions	Symbol	Device	Min	Тур	Max	Units
Inhibit Voltage	I_F = rated I_{FT} , MT1-MT2 voltage above	Viu All			20	V	
	which device will not trigger off-state	VIН	V _{IH} All			20	v
Leakage in Inhibited State	I_F = rated I_F , rated V_{DRM} , off-state	I _{DRM2}	All			500	μA

Note

1. Test voltage must be applied within dv/dt rating.

 All devices are guaranteed to trigger at an I_F value less than or equal to max I_{FT}. Therefore, recommended operating I_F lies between max I_{FT} (15 mA for MOC3031M & MOC3041M, 10 mA for MOC3032M & MOC3042M, 5 mA for MOC3033M & MOC3043M) and absolute max I_F (60 mA).

3. This is static dv/dt. See Figure 9 for test circuit. Commutating dv/dt is a function of the load-driving thyristor(s) only.



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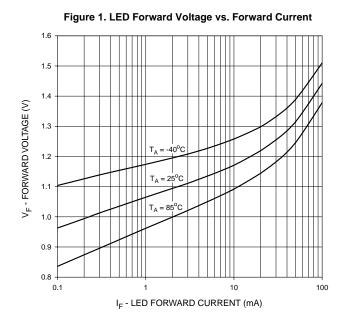


Figure 2. On-State Characteristics

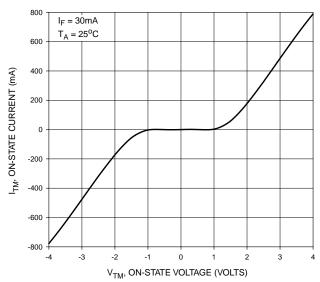


Figure 3. Trigger Current vs. Temperature

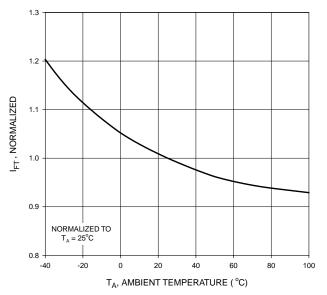
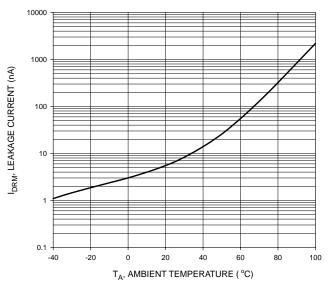


Figure 4. Leakage Current, IDRM vs. Temperature





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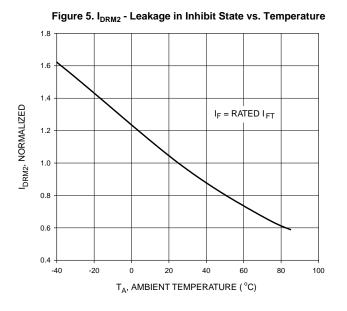


Figure 6. LED Current Required to Trigger vs. LED Pulse Width

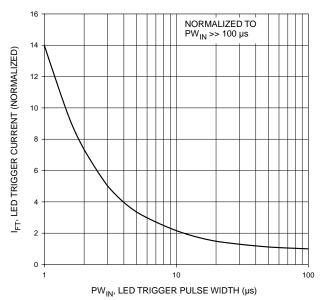


Figure 7. Holding Current, I_H vs. Temperature

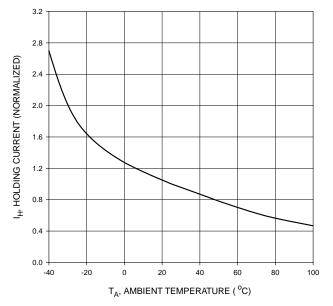
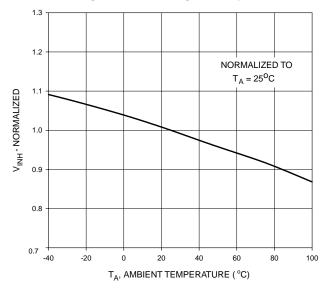
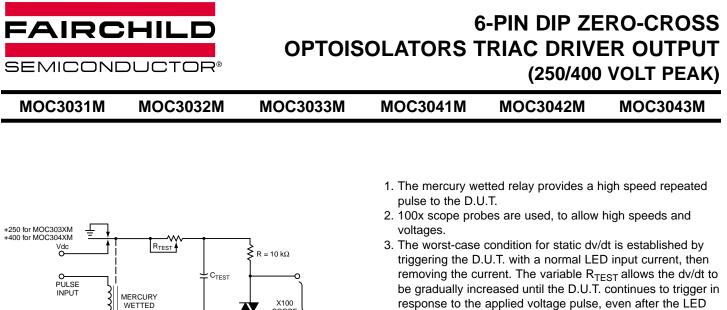
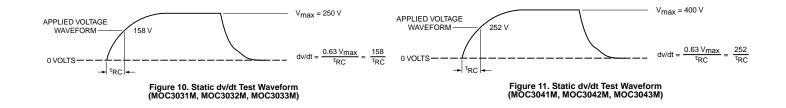


Figure 8. Inhibit Voltage vs. Temperature





response to the applied voltage pulse, even after the LED current has been removed. The dv/dt is then decreased until the D.U.T. stops triggering. ^TRC is measured at this point and recorded.



SCOPE

PROBE

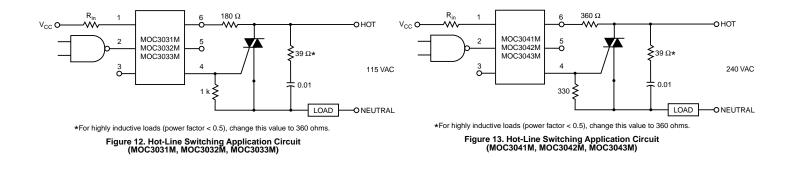
D.U.T.

RELAY

Figure 9. Static dv/dt Test Circuit

Typical circuit (Fig 12, 13) for use when hot line switching is required. In this circuit the "hot" side of the line is switched and the load connected to the cold or neutral side. The load may be connected to either the neutral or hot line.

Rin is calculated so that I_F is equal to the rated I_{FT} of the part, 5 mA for the MOC3033M and MOC3043M, 10 mA for the MOC3032M and MOC3042M, or 15 mA for the MOC3031M and MOC3041M. The 39 ohm resistor and 0.01 µF capacitor are for snubbing of the triac and may or may not be necessary depending upon the particular triac and load used.





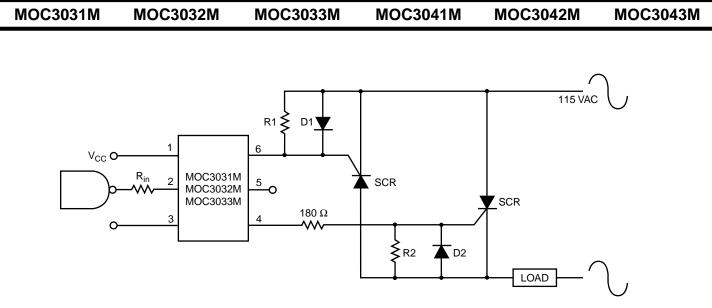
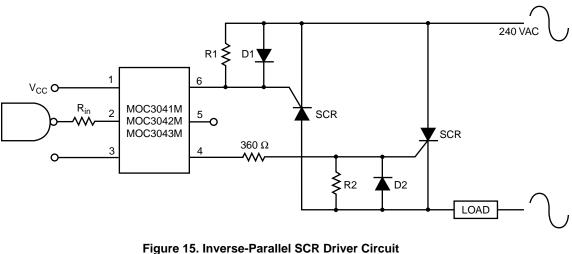


Figure 14. Inverse-Parallel SCR Driver Circuit (MOC3031M, MOC3032M, MOC3033M)

Suggested method of firing two, back-to-back SCR's with a Fairchild triac driver. Diodes can be 1N4001; resistors, R1 and R2, are optional 1 k ohm.



(MOC3041M, MOC3042M, MOC3043M)

Suggested method of firing two, back-to-back SCR's with a Fairchild triac driver. Diodes can be 1N4001; resistors, R1 and R2, are optional 330 ohm.

Note: This optoisolator should not be used to drive a load directly. It is intended to be a trigger device only.



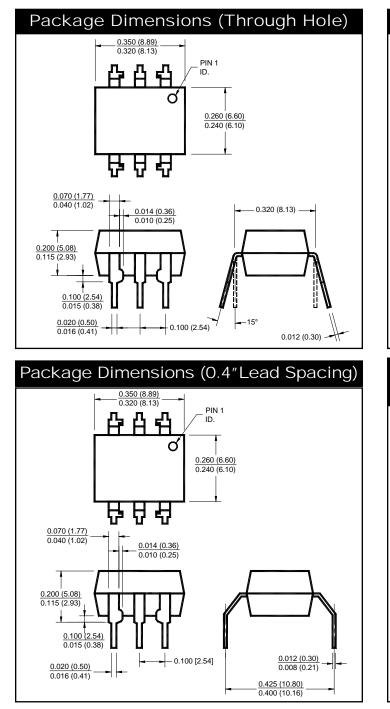
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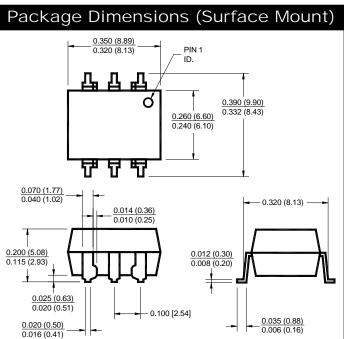
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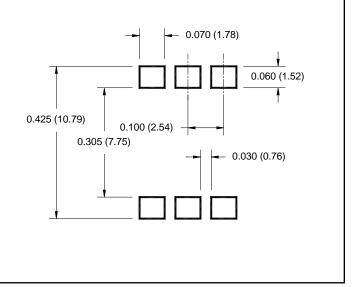
MOC3042M

MOC3043M





Recommended Pad Layout for Surface Mount Leadform



NOTE

All dimensions are in inches (millimeters)



MOC3032M

6-PIN DIP ZERO-CROSS OPTOISOLATORS TRIAC DRIVER OUTPUT (250/400 VOLT PEAK)

MOC3031M

MOC3033M

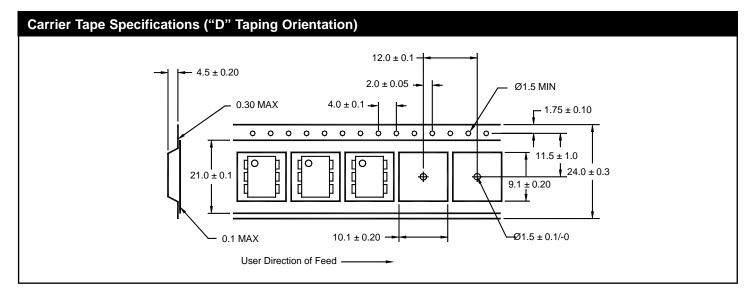
MOC3041M

MOC3042M MC

MOC3043M

ORDERING INFORMATION

Option	Order Entry Identifier	Description
S	S	Surface Mount Lead Bend
SR2	SR2	Surface Mount; Tape and reel
Т	Т	0.4" Lead Spacing
V	V	VDE 0884
TV	TV	VDE 0884, 0.4" Lead Spacing
SV	SV	VDE 0884, Surface Mount
SR2V	SR2V	VDE 0884, Surface Mount, Tape & Reel



NOTE

All dimensions are in inches (millimeters)



MOC3031M MOC3032M MOC3033M MOC3041M MOC3042M MOC3	043M
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